NSN 5961-01-309-1609

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View Online at https://aerobasegroup.com/nsn/5961-01-309-1609 **Inclosure Material:** Ceramic **Overall Length:** Between 0.560 inches and 0.650 inches **Terminal Length:** Between 0.500 inches and 0.580 inches **Overall Height:** Between 0.140 inches and 0.190 inches **Overall Width:** Between 0.380 inches and 0.420 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-22oab **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 4.0 gate to source threshold voltage **Current Rating Per Characteristic:** 15.00 amperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 40.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: